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	SEMI CONDUCTOR

40V N-Channel Enhancement Mode MOSFET

Voltage

Current 40 A

Features

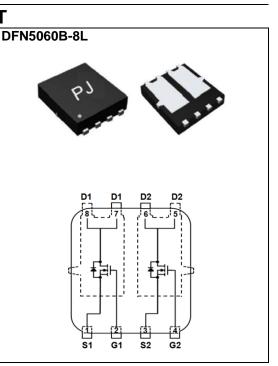
• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@8A<10.5m\Omega$

40 V

- R_{DS(ON)}, V_{GS}@4.5V, I_D@4A<15mΩ
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060B-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0035 ounces, 0.092 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	40		
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T _C =25°C		40		
	T _c =100°C	I _D	25	А	
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	120		
Power Dissipation	T _C =25°C	PD	38.5	W	
	T _C =100°C		19.2		
Continuous Drain Current (Note 4)	T _A =25°C	I _D	9.5	А	
	T _A =70°C		7.5		
Power Dissipation	T _A =25°C	Po	2.0	W	
	T _A =70°C		1.4		
Single Pulse Avalanche Energy (Note 6)		E _{AS}	72	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ extsf{ heta}JC}$	3.9	°C/W	
	Junction to Ambient	R_{\thetaJA}	73.5		

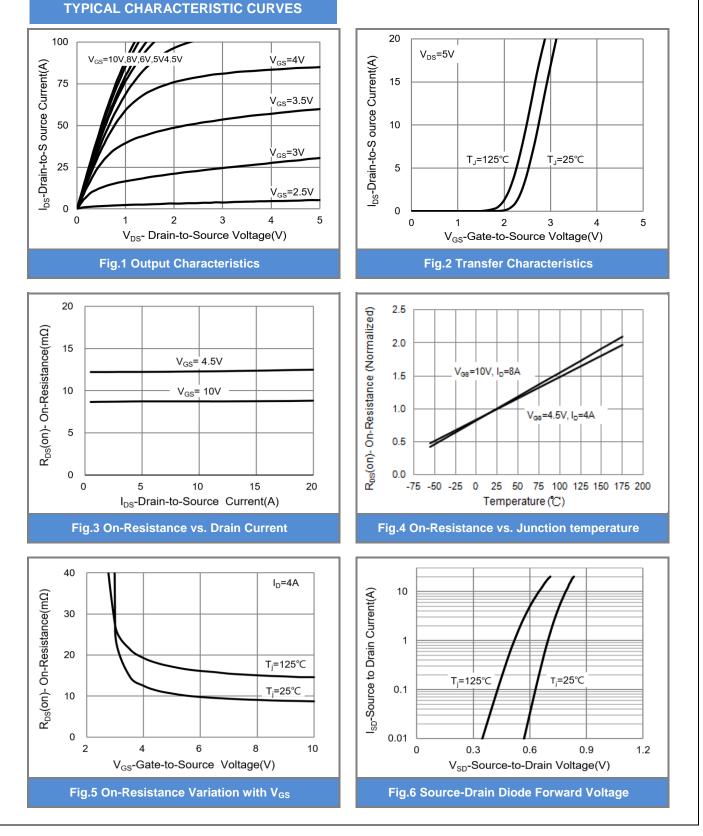


Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		·				
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1	1.7	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =8A	-	9	10.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =4A	-	12	15	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =40V, V_{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V _{DS} =20V, I _D =8A, V _{GS} =10V ^(Note 2,3)	-	22	-	
Gate-Source Charge	Q _{gs}		-	4.2	-	nC
Gate-Drain Charge	Q _{gd}		-	4.0	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V,	-	1258	-	pF
Output Capacitance	Coss		-	134	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	88	-	
Turn-On Delay Time	td _(on)		-	13	-	
Turn-On Rise Time	tr	V _{DS} =15V,I _D =1A, V _{GS} =10V, R _G =3.3Ω (Note 2.3)	-	14	-	
Turn-Off Delay Time	td _(off)		-	45	-	ns
Turn-Off Fall Time	t _f		-	9	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S		-	-	40	A
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.7	1	V

NOTES :

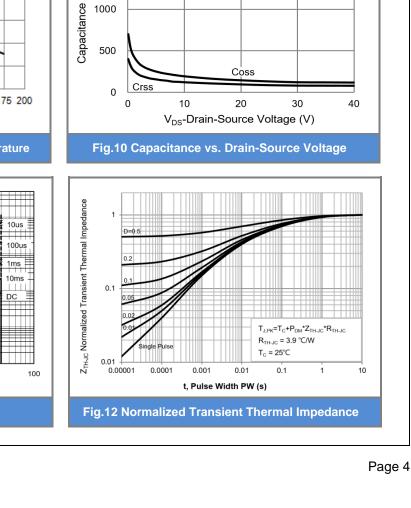
- 1. Pulse width
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =38A, V_{DD} =25V, V_{GS} =10V, Starting T_J =25°C.
- 7. Guaranteed by design, not subject to production testing.

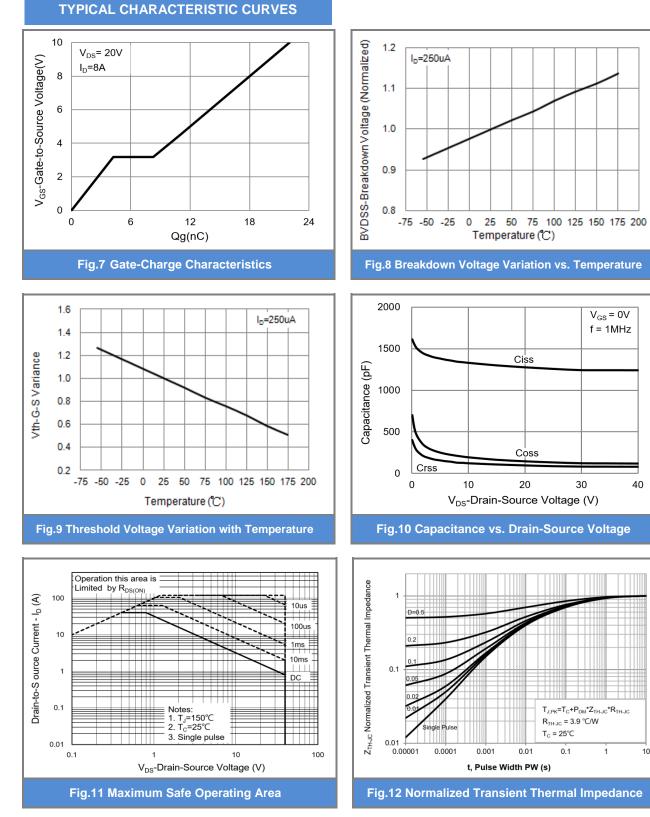


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March 28,2019-REV.00





PJQ5846-AU



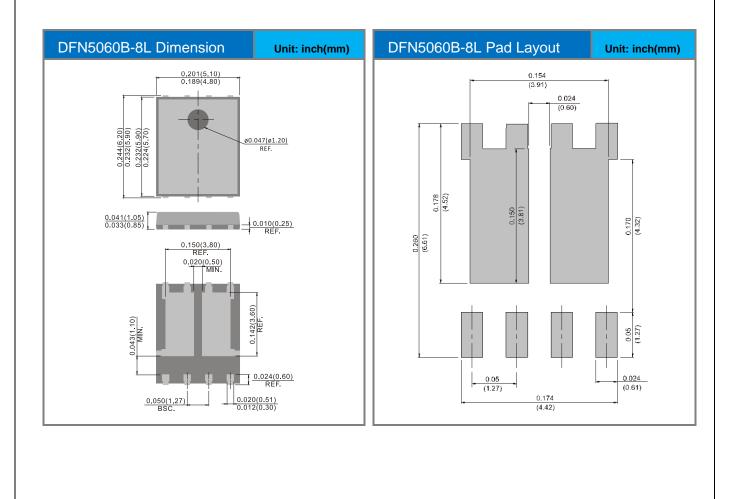




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5846-AU_R2_000A1	DFN5060B-8L	3000pcs / 13" reel	Q5846	Halogen free

Packaging Information & Mounting Pad Layout





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